## NSN 5961-01-323-3875

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-323-3875 **Inclosure Material:** Glass and plastic **Overall Length:** 0.180 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.150 inches **Overall Width:** 0.250 inches **Function For Which Designed:** Switching **End Application:** Armament subsystem **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, instantaneous all semiconductor device diode and 50.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 4.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Two 6.000 in. Wire leads; all semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 8 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No